

TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

**TC74VHC123AF,TC74VHC123AFN,TC74VHC123AFT,TC74VHC123AFK
TC74VHC221AF,TC74VHC221AFN,TC74VHC221AFT,TC74VHC221AFK**

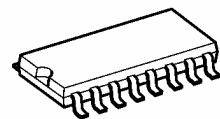
Dual Monostable Multivibrator

TC74VHC123AF/AFN/AFT/AFK Retriggerable

TC74VHC221AF/AFN/AFT/AFK
Non-Retriggerable

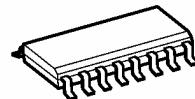
Note: xxxFN (JEDEC SOP) is not available in Japan.

TC74VHC123AF, TC74VHC221AF



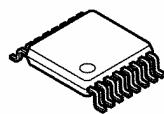
SOP16-P-300-1.27A

TC74VHC123AFN, TC74VHC221AFN



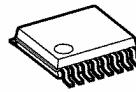
SOL16-P-150-1.27

TC74VHC123AFT, TC74VHC221AFT



TSSOP16-P-0044-0.65A

TC74VHC123AFK, TC74VHC221AFK



VSSOP16-P-0030-0.50

Weight

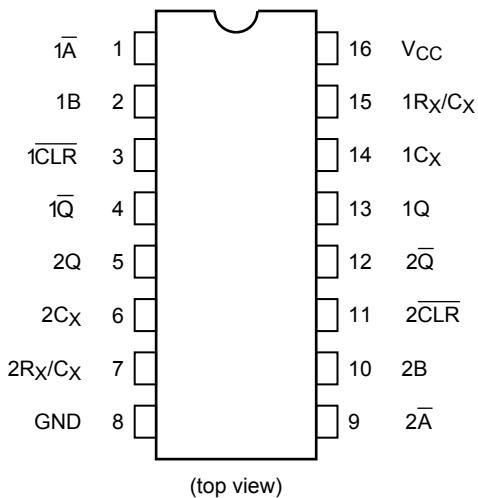
SOP16-P-300-1.27A : 0.18 g (typ.)

SOL16-P-150-1.27 : 0.13 g (typ.)

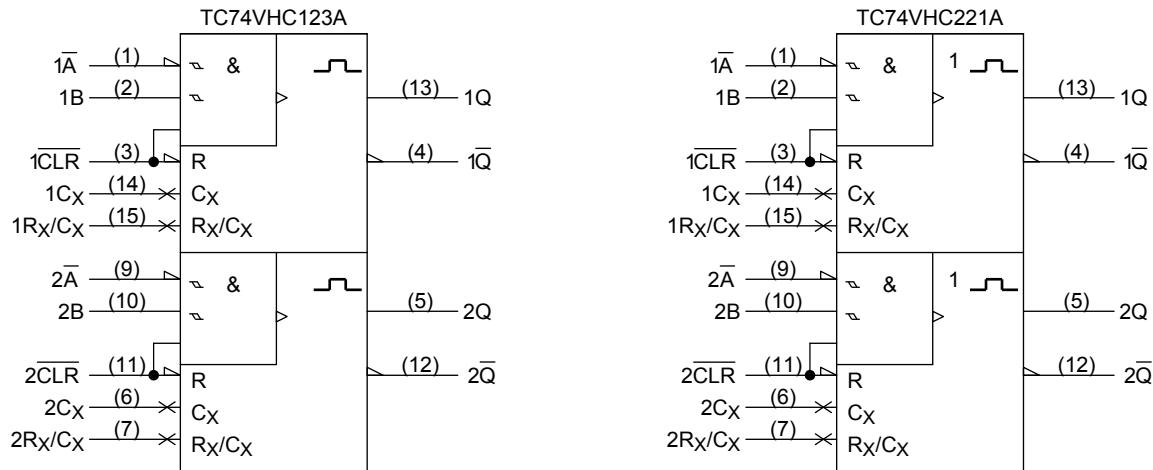
TSSOP16-P-0044-0.65A : 0.06 g (typ.)

VSSOP16-P-0030-0.50 : 0.02 g (typ.)

Pin Assignment



IEC Logic Symbol

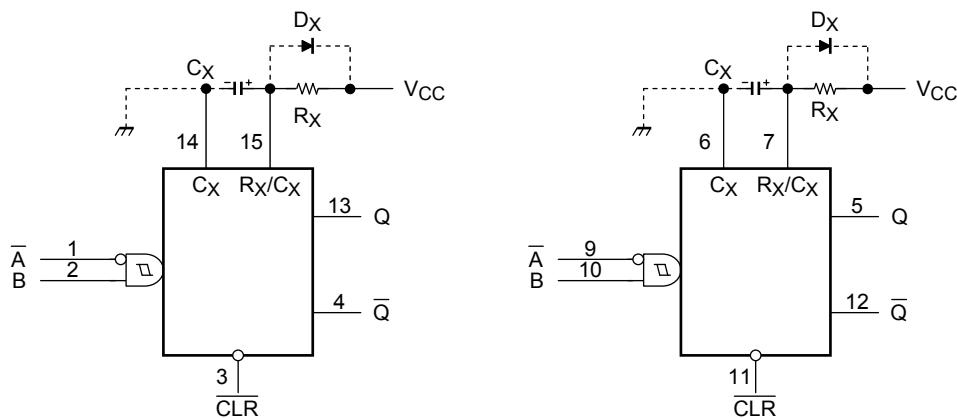


Truth Table

Inputs			Outputs		Function
\bar{A}	B	CLR	Q	\bar{Q}	
↓	H	H	↑	↓	Output Enable
X	L	H	L	H	Inhibit
H	X	H	L	H	Inhibit
L	↑	H	↑	↓	Output Enable
L	H	↑	↑	↓	Output Enable
X	X	L	L	H	Reset

X: Don't care

Block Diagram (Note 1) (Note 2)



Note 1: C_x , R_x , D_x are external

Capacitor, resistor, and diode, respectively.

Note 2: External clamping diode, D_x :

The external capacitor is charged to V_{CC} level in the wait state, i.e. when no trigger is applied.

If the supply voltage is turned off, C_x is discharged mainly through the internal (parasitic) diode. If C_x is sufficiently large and V_{CC} drops rapidly, there will be some possibility of damaging the IC through inrush current or latch-up. If the capacitance of the supply voltage filter is large enough and V_{CC} drops slowly, the inrush current is automatically limited and damage to the IC is avoided.

The maximum value of forward current through the parasitic diode is ± 20 mA.

In the case of a large C_x , the limit of fall time of the supply voltage is determined as follows:

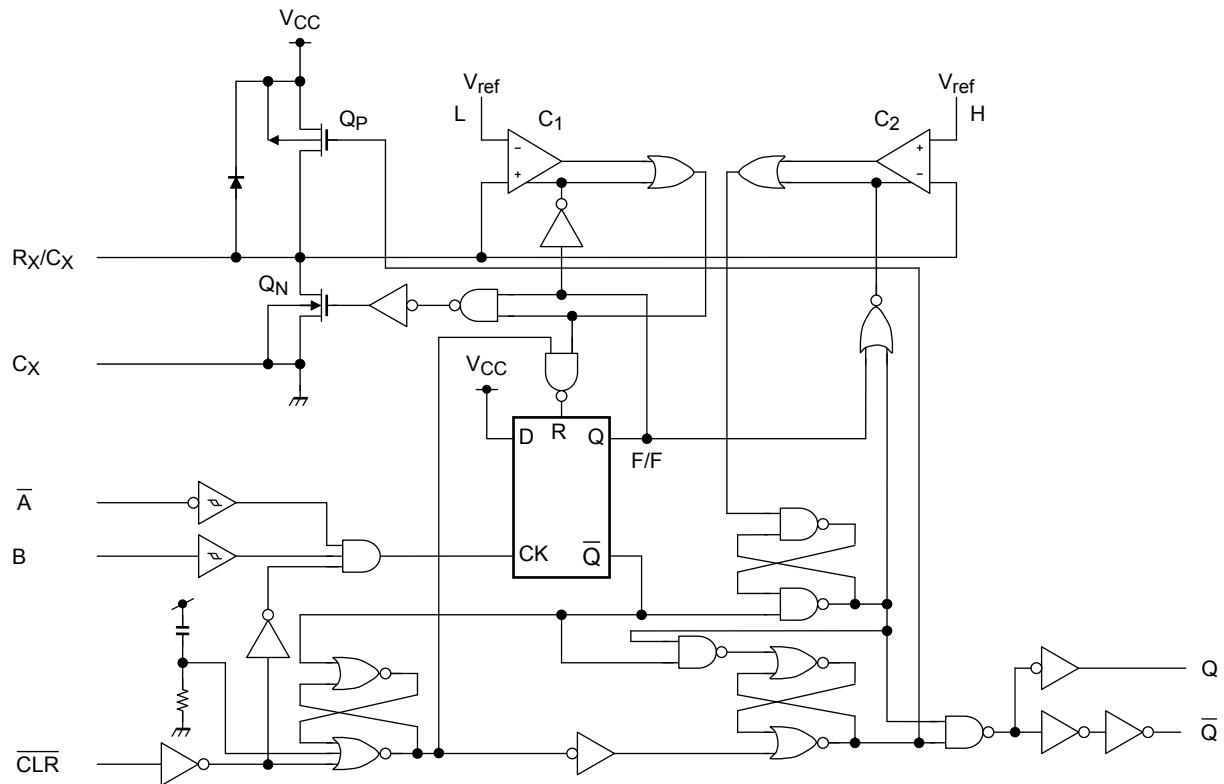
$$t_f \geq (V_{CC} - 0.7) C_x / 20 \text{ mA}$$

(t_f is the time between the supply voltage turn off and the supply voltage reaching 0.4 V_{CC} .)

In the even a system does not satisfy the above condition, an external clamping diode (D_x) is needed to protect the IC from inrush current.

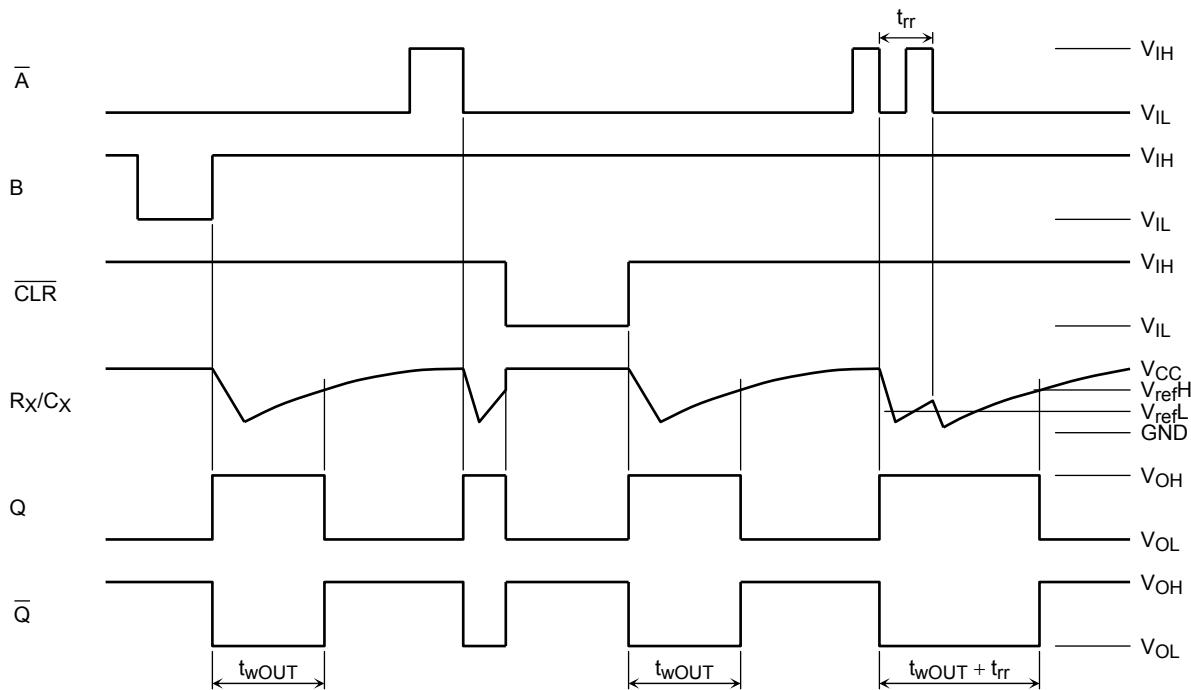
System Diagram

TC74VHC123A



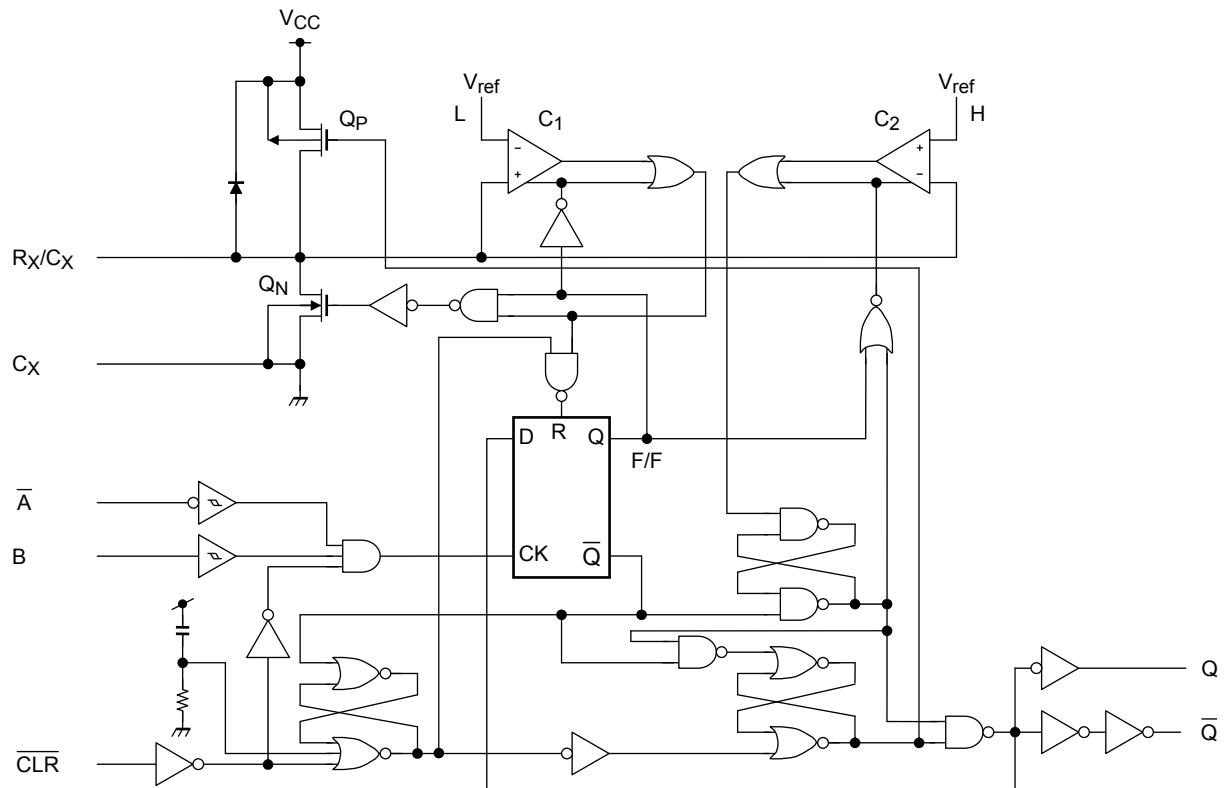
Timing Chart

TC74VHC123A



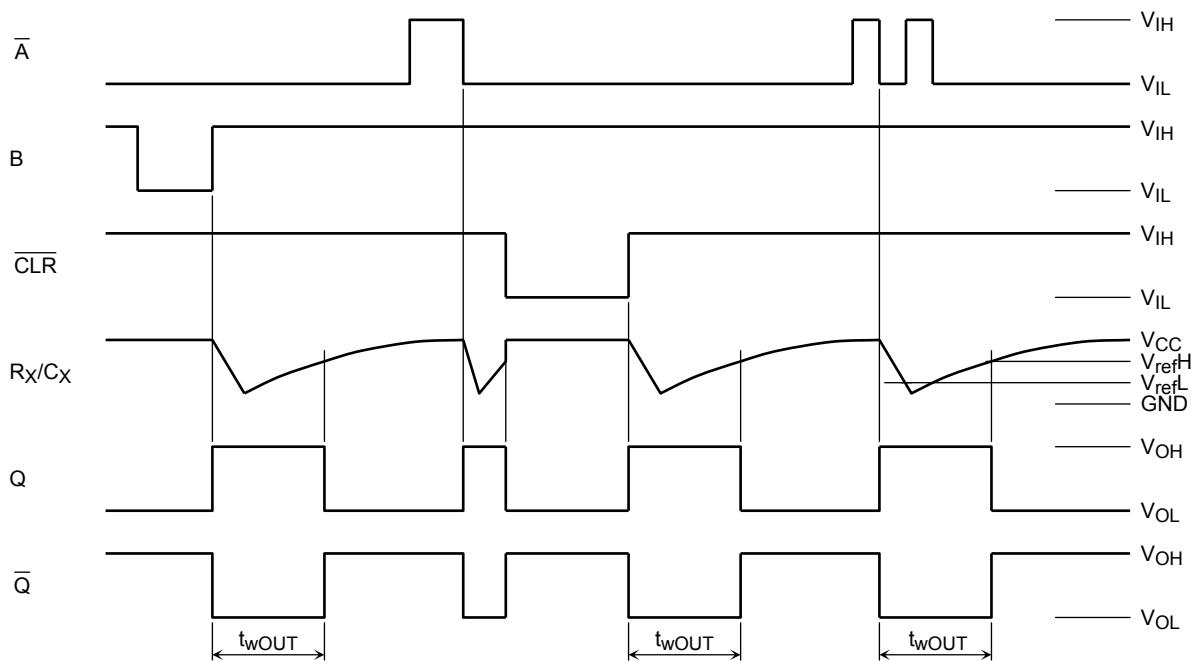
System Diagram

TC74VHC221A



Timing Chart

TC74VHC221A



Functional Description

(1) Standby state

The external capacitor (Cx) is fully charged to VCC in the stand-by state. That means, before triggering, the QP and QN transistors which are connected to the Rx/Cx node are in the off state. Two comparators that relate to the timing of the output pulse, and two reference voltage supplies turn off. The total supply current is only leakage current.

(2) Trigger operation

Trigger operation is effective in any of the following three cases. First, the condition where the \bar{A} input is low, and the B input has a rising signal; second, where the B input is high, and the \bar{A} input has a falling signal; and third, where the \bar{A} input is low and the B input is high, and the \bar{CLR} input has a rising signal.

After a trigger becomes effective, comparators C1 and C2 start operating, and QN is turned on. The external capacitor discharges through QN. The voltage level at the Rx/Cx node drops. If the Rx/Cx voltage level falls to the internal reference voltage V_{refL} , the output of C1 becomes low. The flip-flop is then reset and QN turns off. At that moment C1 stops but C2 continues operating.

After QN turns off, the voltage at the Rx/Cx node starts rising at a rate determined by the time constant of external capacitor Cx and resistor Rx.

Upon triggering, output Q becomes high, following some delay time of the internal F/F and gates. It stays high even if the voltage of Rx/Cx changes from falling to rising. When Rx/Cx reaches the internal reference voltage V_{refH} , the output of C2 becomes low, the output Q goes low and C2 stops its operation. That means, after triggering, when the voltage level of the Rx/Cx node reaches V_{refH} , the IC returns to its MONOSTABLE state.

With large values of Cx and Rx, and ignoring the discharge time of the capacitor and internal delays of the IC, the width of the output pulse, t_w (OUT), is as follows:

$$t_w(\text{OUT}) = 1.0 \cdot Cx \cdot Rx$$

(3) Retrigger operation (TC74VHC123A)

When a new trigger is applied to either input \bar{A} or B while in the MONOSTABLE state, it is effective only if the IC is charging Cx. The voltage level of the Rx/Cx node then falls to V_{refL} level again. Therefore the Q output stays high if the next trigger comes in before the time period set by Cx and Rx.

If the new trigger is very close to previous trigger, such as an occurrence during the discharge cycle, it will have no effect.

The minimum time for a trigger to be effective 2nd trigger, t_{rr} (min.), depends on VCC and CX.

(4) Reset operation

In normal operation, the \bar{CLR} input is held high. If \bar{CLR} is low, a trigger has no effect because the Q output is held low and the trigger control F/F is reset. Also, QP turns on and Cx is charged rapidly to VCC.

This means if \bar{CLR} is set low, the IC goes into a wait state.

Absolute Maximum Ratings (Note)

Characteristics	Symbol	Rating	Unit
Supply voltage range	V_{CC}	–0.5 to 7.0	V
DC input voltage	V_{IN}	–0.5 to 7.0	V
DC output voltage	V_{OUT}	–0.5 to $V_{CC} + 0.5$	V
Input diode current	I_{IK}	–20	mA
Output diode current	I_{OK}	± 20	mA
DC output current	I_{OUT}	± 25	mA
DC V_{CC} /ground current	I_{CC}	± 50	mA
Power dissipation	P_D	180	mW
Storage temperature	T_{STG}	–65 to 150	°C

Note: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc.).

Operating Ranges (Note 1)

Characteristics	Symbol	Rating	Unit
Supply voltage	V_{CC}	2.0 to 5.5	V
Input voltage	V_{IN}	0 to 5.5	V
Output voltage	V_{OUT}	0 to V_{CC}	V
Operating temperature	T_{OPR}	–40 to 85	°C
Input rise and fall time	dt/dv	0 to 100 ($V_{CC} = 3.3 \pm 0.3$ V) 0 to 20 ($V_{CC} = 5 \pm 0.5$ V)	ns/V
External capacitor	C_X	No limitation (Note 2)	F
External resistor	R_X	≥ 5 k (Note 3) ($V_{CC} = 2.0$ V) ≥ 1 k (Note 3) ($V_{CC} \geq 3.0$ V)	Ω

Note 1: The operating ranges must be maintained to ensure the normal operation of the device.
Unused inputs must be tied to either VCC or GND.

Note 2: The maximum allowable values of C_X and R_X are a function of leakage of capacitor C_X , the leakage of TC74VHC123A/221A, and leakage due to board layout and surface resistance.

Susceptibility to externally induced noise signals may occur for $R_X > 1$ MΩ.

Electrical Characteristics

DC Characteristics

Characteristics	Symbol	Test Condition		V _{CC} (V)	Ta = 25°C			Ta = -40 to 85°C		Unit		
					Min	Typ.	Max	Min	Max			
High-level input voltage	V _{IH}	—	—	2.0	1.50	—	—	1.50	—	V		
				3.0 to 5.5	V _{CC} × 0.7	—	—	V _{CC} × 0.7	—			
Low-level input voltage	V _{IL}	—	—	2.0	—	—	0.50	—	0.50	V		
				3.0 to 5.5	—	—	V _{CC} × 0.3	—	V _{CC} × 0.3			
High-level output voltage	V _{OH}	V _{IN} = V _{IH} or V _{IL}	I _{OH} = -50 μA	2.0	1.9	2.0	—	1.9	—	V		
				3.0	2.9	3.0	—	2.9	—			
Low-level output voltage	V _{OL}			4.5	4.4	4.5	—	4.4	—			
				I _{OH} = -4 mA	3.0	2.58	—	2.48	—			
				I _{OH} = -8 mA	4.5	3.94	—	3.80	—			
I _{OL} = 50 μA	2.0			—	0.0	0.1	—	V				
				3.0	—	0.0	0.1		—	0.1		
				4.5	—	0.0	0.1		—	0.1		
I _{OL} = 4 mA	3.0			—	—	0.36	—					
I _{OL} = 8 mA	4.5			—	—	0.36	—					
Input leakage current	I _{IN}	V _{IN} = 5.5 V or GND		0 to 5.5	—	—	±0.1	—	±1.0	μA		
R _X /C _X terminal off-state current	I _{IN}	V _{IN} = V _{CC} or GND		5.5	—	—	±0.25	—	±2.5	μA		
Quiescent supply current	I _{CC}	V _{IN} = V _{CC} or GND		5.5	—	—	4.0	—	40.0	μA		
Active-state supply current (Note)	I _{CC}	V _{IN} = V _{CC} or GND R _X /C _X = 0.5 V _{CC}	3.0 4.5 5.5	—	160	250	—	280	—	μA		
				—	380	500	—	650	—			
				—	560	750	—	975	—			

Note: Per circuit

Timing Requirements (input: $t_r = t_f = 3$ ns)

Characteristics	Symbol	Test Condition	Ta = 25°C		Ta = -40 to 85°C	Unit
			V _{CC} (V)	Typ.		
Minimum pulse width (t_w)	t_w (L) t_w (H)	—	3.3 ± 0.3	—	5.0	5.0
			5.0 ± 0.5	—	5.0	5.0
Minimum clear width (\overline{CLR})	t_w (L)	—	3.3 ± 0.3	—	5.0	5.0
			5.0 ± 0.5	—	5.0	5.0
(Note)	t_{rr}	$R_X = 1$ kΩ	3.3 ± 0.3	60	—	—
		$C_X = 100$ pF	5.0 ± 0.5	39	—	—
		$R_X = 1$ kΩ	3.3 ± 0.3	1.5	—	—
		$C_X = 0.01$ μF	5.0 ± 0.5	1.2	—	—

Note: For TC74VHC123A only

AC Characteristics (input: $t_r = t_f = 3$ ns)

Characteristics	Symbol	Test Condition	Ta = 25°C			Ta = -40 to 85°C		Unit	
			V _{CC} (V)	C _L (pF)	Min	Typ.	Max		
Propagation delay time (\overline{A} , B-Q, \overline{Q})	t_{pLH} t_{pHL}	—	3.3 ± 0.3	15	—	13.4	20.6	1.0	24.0
				50	—	15.9	24.1	1.0	27.5
			5.0 ± 0.5	15	—	8.1	12.0	1.0	14.0
				50	—	9.6	14.0	1.0	16.0
	t_{pLH} t_{pHL}	—	3.3 ± 0.3	15	—	14.5	22.4	1.0	26.0
				50	—	17.0	25.9	1.0	29.5
			5.0 ± 0.5	15	—	8.7	12.9	1.0	15.0
				50	—	10.2	14.9	1.0	17.0
Propagation delay time (\overline{CLR} trigger-Q, \overline{Q})	t_{pLH} t_{pHL}	—	3.3 ± 0.3	15	—	10.3	15.8	1.0	18.5
				50	—	12.8	19.3	1.0	22.0
			5.0 ± 0.5	15	—	6.3	9.4	1.0	11.0
				50	—	7.8	11.4	1.0	13.0
	t_{wOUT}	$C_X = 28$ pF $R_X = 2$ kΩ	3.3 ± 0.3	50	—	160	240	—	300
					—	133	200	—	240
		$C_X = 0.01$ μF $R_X = 10$ kΩ	3.3 ± 0.3	50	90	100	110	90	110
					90	100	110	90	110
		$C_X = 0.1$ μF $R_X = 10$ kΩ	3.3 ± 0.3	50	0.9	1.0	1.1	0.9	1.1
					0.9	1.0	1.1	0.9	1.1
Output pulse width error between circuits (in same package)	Δt_{wOUT}	—	—	—	±1	—	—	—	%
Input capacitance	C _{IN}	—	—	—	4	10	—	10	pF
Power dissipation capacitance	C _{PD}	(Note)	—	73	—	—	—	—	pF

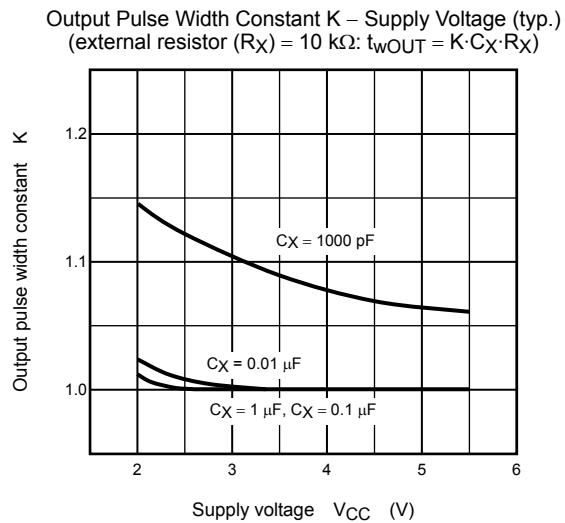
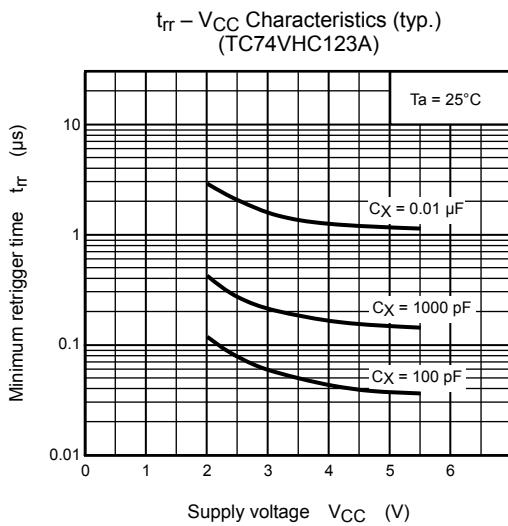
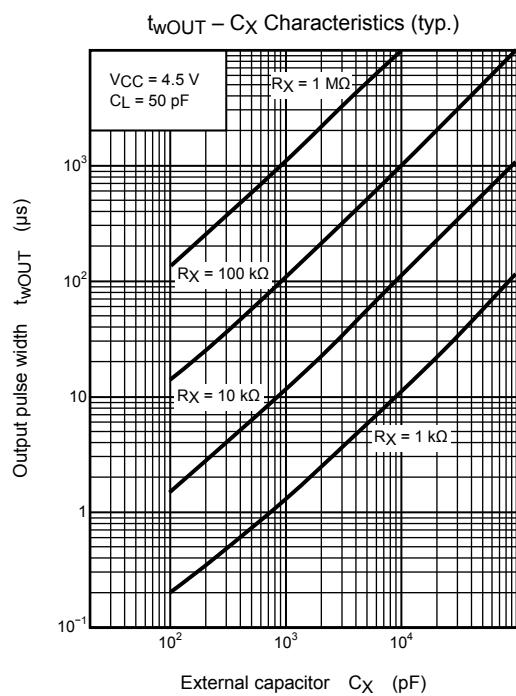
Note: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation:

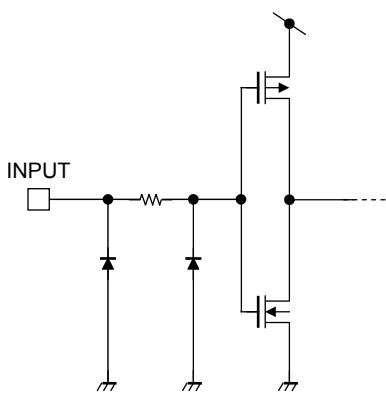
$$I_{CC}(\text{opr}) = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC} \cdot \text{Duty}/100 + I_{CC}/2 \text{ (per circuit)}$$

(I_{CC}: active supply current)

(duty: %)



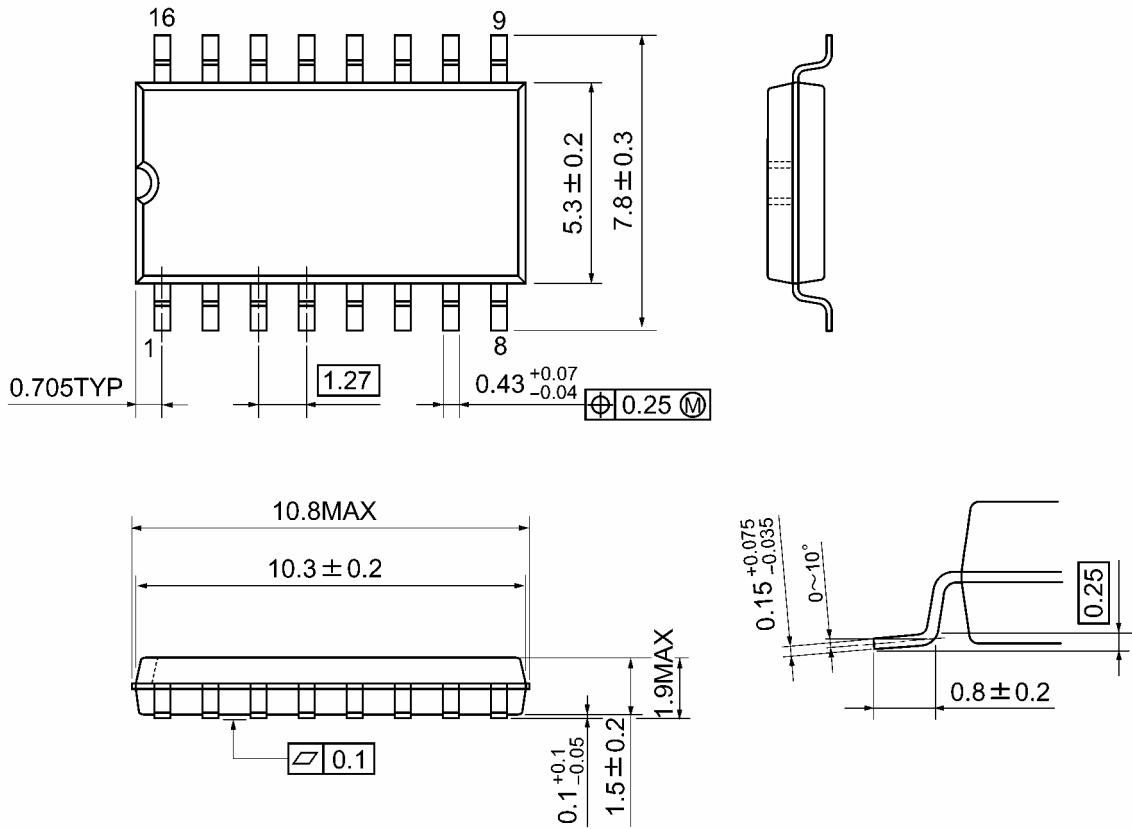
Input Equivalent Circuit



Package Dimensions

SOP16-P-300-1.27A

Unit: mm

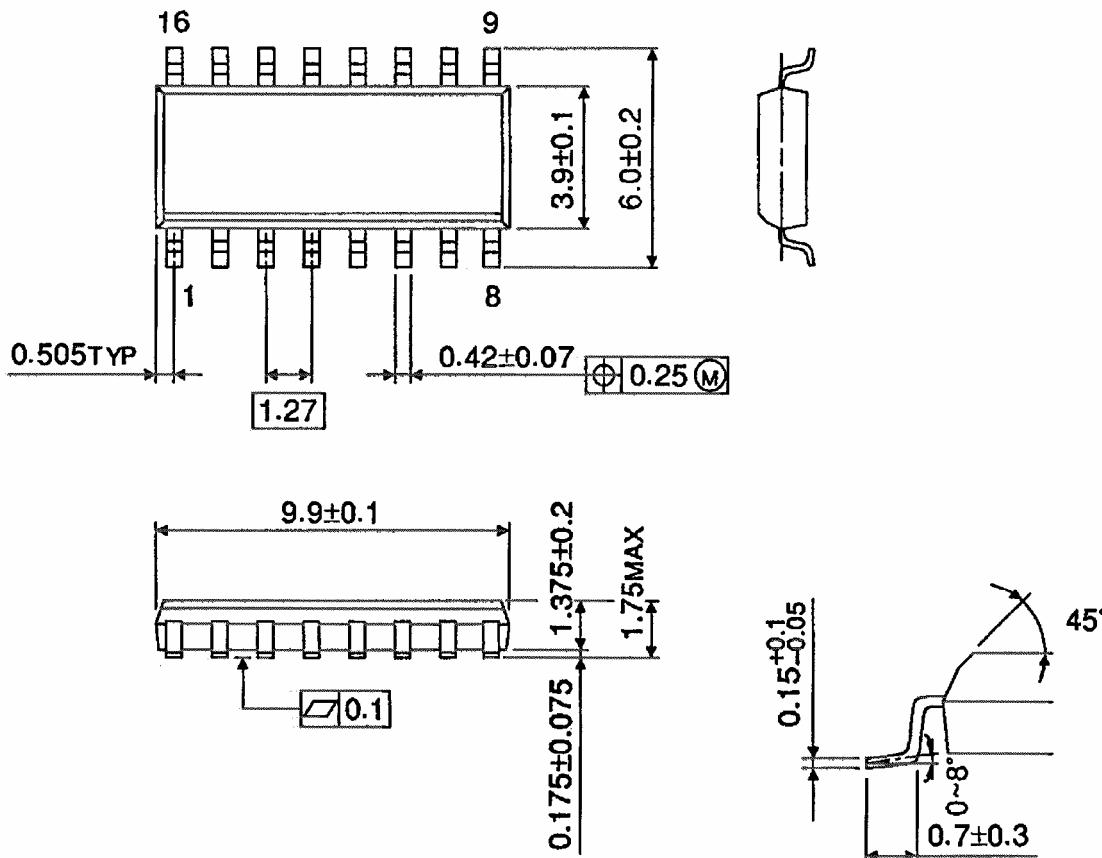


Weight: 0.18 g (typ.)

Package Dimensions (Note)

SOL16-P-150-1.27

Unit : mm



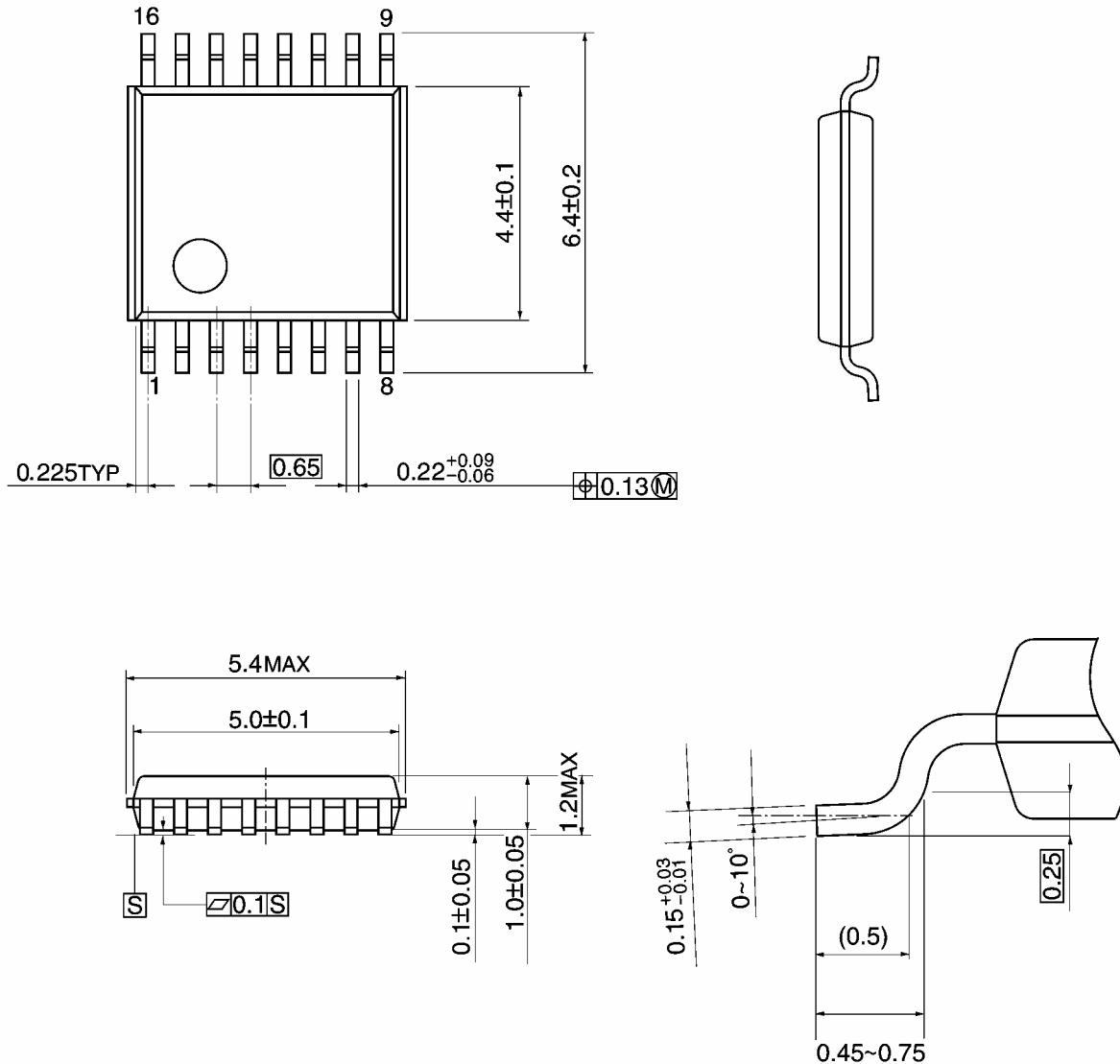
Note: This package is not available in Japan.

Weight: 0.13 g (typ.)

Package Dimensions

TSSOP16-P-0044-0.65A

Unit: mm

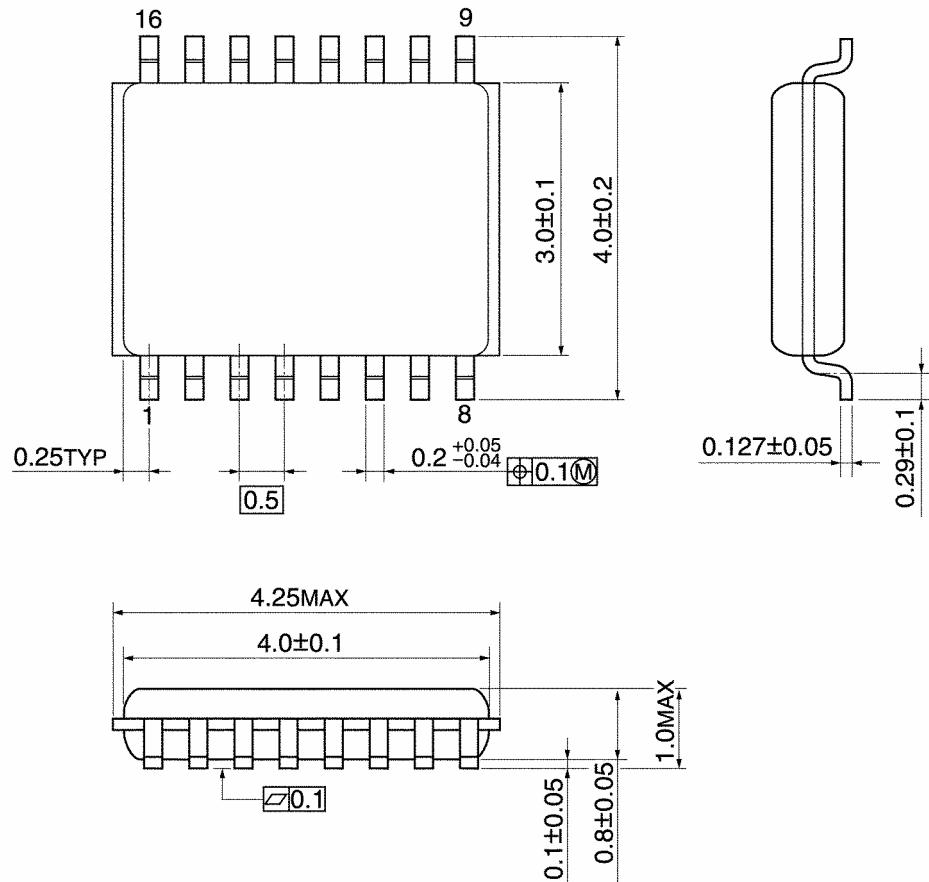


Weight: 0.06 g (typ.)

Package Dimensions

VSSOP16-P-0030-0.50

Unit: mm



Weight: 0.02 g (typ.)

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20070701-EN GENERAL

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